Integrating metalloporphycenes into p-type NiO-based dye-sensitized solar cells

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In the current work, we have explored a novel synthetic route towards metalated porphycenes and their use in p-type NiO-based dye-sensitized solar cells. Particular emphasis is placed on the influence that the relative positioning of the anchoring group exerts on the DSSC performance.

Factors that favor dye-sensitized solar cells (DSSCs) as a key technology in solar-energy conversion schemes include low purity requirements and easy accessibility, low costs, fast processing, and simple up-scaling. DSSCs have been rendered even more attractive by recent progress in solid-state devices and substrate flexibility. 1, 2 To date, record efficiencies as high as 13% have been reported for n-type DSSCs. 3 However, efficient p-type DSSCs, which complement n-type DSSCs in, for example, tandem configurations, are necessary for obtaining values beyond 13%, and are therefore the subject of intensive investigation. 4

Regardless of whether the semiconductor materials are n- or p-type, the chromophore attached to the semiconductor electrode is decisive in terms of light harvesting, charge transfer, and charge transport. Very diverse organic or inorganic chromophores have recently been tested in both types of DSSCs. 5-8 Fine tuning synthetic parameters such as the metalation of the chromophore, the nature of the anchor, and the bridge that links the chromophore to the anchor, have made control over important characteristics like highly effective charge separation, reduced charge recombination, and long term stability possible. 9-12

Semiconductor nickel oxide (NiO) stands out as an electrode material for p-type DSSCs. 7, 13-15 This has triggered the design of novel light-harvesting and electron-accepting chromophores. 13 We have focused on porphycenes because of their similarity to porphyrins and phthalocyanines. 16, 17 In contrast to the electron-donating features of porphyrins and phthalocyanines, which are widely used in n-type DSSCs, 8, 18 porphycenes are strong electron acceptors, making them more suitable building blocks for p-type DSSCs. To the best of our knowledge, only a few examples of the use of free-base porphycenes in solar energy devices are known to date. 19, 20

We now report two major achievements. The first is the development of a new synthetic route to nickel porphycenes, which have barely been investigated previously. We have characterized the novel nickel porphycenes physicochemical and computational techniques. Second, we have used these nickel porphycenes in p-type NiO-based DSSCs. We have been able to rationalize the overall performance of the resulting devices in terms of the position and the nature of the anchor groups and, in turn, to establish new guidelines to designing novel electron acceptors.

Scheme 1. Synthetic routes towards porphycenes P1-P3.

Three different nickel porphycenes were prepared – Scheme 1. Experimental details are given in the supporting information (SI). In order to obtain the target porphycenes, the 2,7,12,17-tetra-n-propylporphycenato nickel (I) was chosen as the starting material. Firstly, the peripheral alkyl chains ensure sufficient solubility in a wide variety of solvents. Secondly, the well-established chemistry of I allows preparing the target featuring a vinyl linker, which has been established as an efficient linker for porphyrins in n-type DSSCs. 21 Thirdly, we decided to test the viability of two different anchoring groups, that is, dicarboxyl and cyanocarboxy groups. Finally, we focused only on nickel porphycene to avoid metalations when using free-base derivatives.

In detail, I is available in good yields through a well-known eight-step synthesis 16 and was reacted with 3-dimethylaminoacrolein under Vilsmeier conditions to obtain formylvinyl-functionalized porphycenes in accordance with a previously published procedure. 22 The two isomers obtained were separated by repeated column chromatography. 2 was then reacted in a Knoevenagel reaction with malonic acid in the presence of ammonium acetate, which led to dicarboxylic acid P1 in 56% yield after purification by column chromatography. Similarly, aldehyde 3 was reacted to give the corresponding P2 in 46%. P3, which bears a cyanoacetic acid...
anchoring group, was generated from 3 in 75% yield as a complement to P2.

Absorption and fluorescence spectroscopy and electrochemical assays provide insight into the electronic properties of the porphycenes. The absorption spectra of P1, P2, and P3 feature Soret and Q-band absorptions at 400 and 600 nm, respectively (see Figure 1 and Table S1). As for porphyrins and phthalocyanines, 17, 23, 24 comparing the absorption spectra of P1, P2, and P3 to that of the free-base porphycene discloses the impact of the metalation and of the anchor substituent. 16, 25

Figure 1 Steady-state absorption spectra of P1, P2, and P3 in DMF.

Metalation causes bathochromic shifts of the absorption maxima from 370 nm to 395, 407, and 412 nm for P1, P2, and P3, respectively. 17, 24 The linker substituents lower the overall symmetry from D_{2h} to C_{s} 16 resulting in broadening of the Soret band absorption in the 350 to 500 nm range. 17, 23

Significantly red-shifted and broadened Soret and Q-band absorptions are found on changing the position of the anchor substituent from, for example, the pyrrole-rings in P1 to the ethylene bridges in P2 and P3. 17 In P3, the presence of electron-withdrawing cyanato-groups further red-shifts the Soret band absorptions due to coplanarity. 17, 26 Fluorescence was not observed for any of the porphycenes because of fast non-radiative deactivation processes, which are well known for Ni^{2+}-based porphyrins. 27, 28

P1, P2, and P3 exhibit similar redox characteristics; three quasi-reversible reductions around -0.80/-1.09/-1.56, -0.88/-1.16/-1.61, and -0.99/-1.27/-1.78 V and two quasi-reversible oxidations around 0.98/1.31, 1.02/1.22 and 0.89/1.05 V versus NHE (see Figure S4). Porphycenes are slightly easier (1.02 V) to reduce and slightly more difficult (~0.80 V) to oxidize than free-base and nickel porphyrins, confirming their electron accepting character (Table S2). 29-31 Figure S5 shows the reduction and oxidation potentials of P1, P2, and P3, the valence band (0.54 V vs. NHE) of NiO, and the redox potential (0.44 V vs. NHE) of the I_{3}/I_{2} couple. 32 Taking these into account, we hypothesize that these novel acceptors are potentially good sensitizers in NiO-based DSSCs.

To verify our hypothesis, we fabricated p-type DSSCs based on NiO electrodes by following the route reported by Sumikura et al. 33 Detailed information is provided in the SI.

Next, the NiO electrodes were immersed in 10^{-4} molar DMF solutions of P1, P2, and P3. Adsorption kinetic experiments, as documented in Figure S9, confirm that the optimum uptake for realizing full electrode coverage is 90 min regardless of the linker and the anchoring group. It is important to point out two aspects. Firstly, the light-harvesting efficiency of the electrodes is similar for all the porphycene electrodes (Figure S9), ensuring a reasonable comparison between the corresponding devices. Secondly, all the porphycenes reveal good photostability once attached onto the electrodes under both room light and 1sun / AM 1.5 illumination conditions – Figure S11.

Finally, the p-type DSSCs were completed with a platinum counter-electrode and LiI/I_{3} (5:1) in acetonitrile as electrolyte. The device performance is summarized in Table S3 and the photocurrent density versus applied voltage graphs are shown in Figure 2.

Figure 2 J-V-curves of p-type NiO-based DSSCs with P1, P2, and P3.

Several trends are discernable on close inspection of the device features. Firstly, the photocurrent densities for devices made with porphycenes that feature anchors at the ethylene bridges, P2 (1.03 mA-cm^{-2}) and P3 (0.82 mA-cm^{-2}), are higher than those for those prepared with P1 (0.77 mA-cm^{-2}), in which the anchor is attached at the pyrrole ring. The latter trend is further corroborated by the incident photon-to-current efficiency (IPCE) spectra. For example, devices with P2 feature the highest Q-band contribution centered at 630 nm. The featureless IPCE spectrum of bare NiO-based devices in the region from 500-750 nm clearly confirms the role of the dyes as sensitizers. Please note that the Soret contribution overlaps with the electrolyte band, hampering any quantitative analysis – Figure S10. Next, among all of the porphycene devices, those with P2 feature the highest open-circuit voltage (V_{oc}) and short-circuit current density (J_{sc}) of 0.078 V and 1.03 mA-cm^{2}, respectively. Therefore, the highest efficiency (0.028 %) was found for P2 devices, followed by efficiencies of 0.021 and 0.019 % for devices with P3 and P1, respectively. In contrast to the photostability of the porphycenes adsorbed on NiO electrodes, DSSCs show low stability. For example, the efficiency increases by around 30% relative to the initial value followed by a fast decay until 50% of the maximum efficiency value at 55 h. Therefore, we conclude that our devices are not fully optimized in terms of...
electrolyte composition. As a confirmation, $J_{\text{sc}}$ versus illumination intensity plots show non-linear trends, indicating a poor balance between regeneration/recombination processes and/or diffusion problems in the electrolyte – Figure S12.\(^{34}\) Nevertheless, our results will be useful towards the design of new porphycenes for highly efficient p-type DSSCs,\(^{35}\) although the performances of our devices are still on a quite moderate level.\(^{1,36-38}\)

In this context, we infer from Figure S5 that similar energetics in any of the combinations of P1, P2, and P3 with NiO, and I$_3$/I$^-$ should lead to constant results, at odds with the experimental results. Only the position and the nature of the anchor remain as the cause of the differences. For instance, the most effective scenario for hole-transfer to the valence band of NiO is apparently found if the anchors are placed at the ethylene bridges (P2 and P3). The electron-withdrawing cyano-groups found in P3, however, retard the hole-transfer and reduce the photocurrent density and the overall device efficiency.

**Figure 3** Orbital into which an electron is promoted in the lowest excited singlet state (S$_1$) for P1 (left) and P2 (right).

To support these ideas, semiempirical (PM6)$^{39}$ unrestricted natural orbital pair excitation configuration interaction (UNOPECII)$^{40}$ calculations were performed to shed light on the interfacial charge injection processes. The systems calculated consisted of P1 and P2 linked to an Ni$_{13}$O$_{13}$$^{2+}$ cluster. The molecular structures of P1 and P2 and the linker/NiO hybrid were optimized, and then joined for the PECI calculations. This guaranteed that the results were not influenced by changes in the binding motif. Next, we analyzed the electronic structure of the lowest-energy excited state of both systems. The charge redistribution upon excitation can be quantified by the summed Coulson atomic charges of dye, bridge, and NiO in the ground and excited states (see Table S4). This reveals that the electronic coupling between P2 and NiO displays a partial transfer of electrons from NiO to the porphycene. For P1, the S$_1$ state is, in stark contrast, characterized by a net electron transfer to NiO and to the bridge. Such a scenario favors the unwanted charge-recombination processes. The difference between the S$_1$ states of the two dyes can be visualized by plotting the orbitals into which the electron is promoted (Fig. 3).

Finally, electrochemical impedance spectroscopy (EIS) measurements were performed (details are given in the SI). The Nyquist and Bode phase plots are shown in Figures S14 and S15, respectively. In addition, the resistance to charge transfer processes (R), and the capacitance (C) are summarized in Tables S5 and S6. For p-type DSSCs, EIS provides insight into charge-transfer processes across the electrode/chromophore and the electrode/electrolyte interfaces with and without illumination, respectively. Under illumination and forward bias, the rate of charge transfer between the electrode and porphycenes should be high and $R_1$ should be low. On the contrary, under dark conditions and forward bias, the rate of charge transfer between the electrolyte and electrode should be low and $R_4$ should be high.\(^{41,42}\) Our observations that the highest photocurrent densities are found for P2 devices are consistent with the above-mentioned guidelines, having the lowest $R_1$ and the highest $R_4$ among all of the tested porphycenes (see Tables S5 and S6). In addition, the rate constant ($k_{\text{et}}$) for electrode/chromophore charge transfer is the highest for P2 devices. In line with the theoretical characterization, P1 devices exhibit the highest $R_1$ and, in turn, the least efficient electron transfer process under operating conditions.

In summary, we document for the first time the synthesis of novel nickel porphycenes, their photophysical and electrochemical features, as well as their application in p-type DSSCs. Molecular-orbital calculations and impedance measurements helped establish a comprehensive understanding of the bottlenecks in the overall device performance. Still, transient absorption spectroscopy and small-angle-X-ray-scattering surface characterization assays are necessary to shed light onto the kinetics of injection, recombination, and regeneration processes as well as the reorganization of the molecules onto the electrode surface. Despite the moderate performances, we believe that future progress in the synthesis will help to establish nickel porphycenes as a new kind of sensitizers for p-type DSSCs. Ongoing work in our laboratory is focused on the aforementioned aspects.

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**Notes and references**

The presented trends are obtained after analyzing several absorptions features, electrode thickness, and electrolyte composition.


